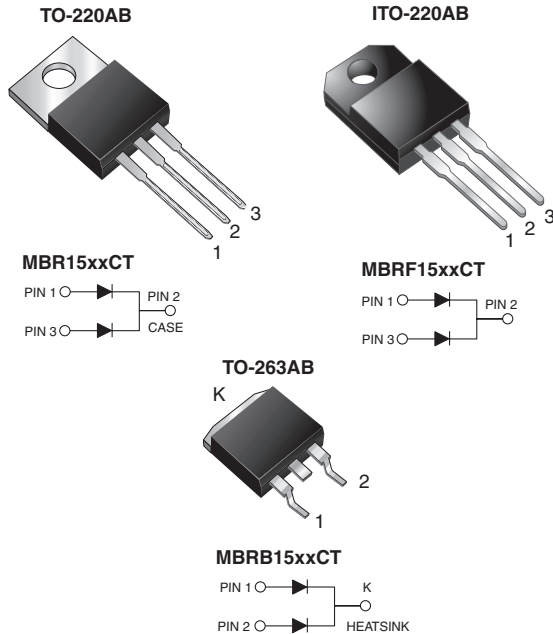


Dual Common-Cathode Schottky Rectifier



FEATURES

- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB and ITO-220AB package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	7.5 A x 2
V_{RRM}	35 V to 60 V
I_{FSM}	150 A
V_F	0.57 V, 0.65 V
T_J max.	150 °C

MAXIMUM RATINGS ($T_C = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	MBR1535CT	MBR1545CT	MBR1550CT	MBR1560CT	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	35	45	50	60	V
Working peak reverse voltage	V_{RWM}	35	45	50	60	V
Maximum DC blocking voltage	V_{DC}	35	45	50	60	V
Maximum average forward rectified current at $T_C = 105$ °C	$I_{F(AV)}$	total device per diode		15		A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}			7.5		A
Peak repetitive reverse surge current per diode at $t_p = 2.0$ μ s, 1 kHz	I_{RRM}			150		A
Peak repetitive reverse surge current per diode at $t_p = 2.0$ μ s, 1 kHz	I_{RRM}	1.0		0.5		A
Voltage rate of change (rated V_R)	dV/dt			10 000		V/ μ s
Operating junction temperature range	T_J			- 65 to + 150		°C

MBR(F,B)1535CT thru MBR(F,B)1560CT

Vishay General Semiconductor



MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR1535CT	MBR1545CT	MBR1550CT	MBR1560CT	UNIT
Storage temperature range	T _{STG}	- 65 to + 175				°C
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500				V

ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	MBR1535CT	MBR1545CT	MBR1550CT	MBR1560CT	UNIT
Maximum instantaneous forward voltage per diode ⁽¹⁾	I _F = 7.5 A	T _C = 25 °C	V _F	-	-	0.75	-	V
	I _F = 7.5 A	T _C = 125 °C		0.57	-	0.65	-	
	I _F = 15 A	T _C = 25 °C		0.84	-	-	-	
	I _F = 15 A	T _C = 125 °C		0.72	-	-	-	
Maximum instantaneous reverse current at rated DC blocking voltage per diode ⁽¹⁾	T _C = 25 °C		I _R	0.1	-	1.0	-	mA
	T _C = 125 °C			15	-	50	-	

Note:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Maximum thermal resistance per diode	R _{θJA}	60	-	60	°C/W
	R _{θJC}	3.0	5.0	3.0	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	MBR1545CT-E3/45	1.85	45	50/tube	Tube
ITO-220AB	MBRF1545CT-E3/45	1.99	45	50/tube	Tube
TO-263AB	MBRB1545CT-E3/45	1.35	45	50/tube	Tube
TO-263AB	MBRB1545CT-E3/81	1.35	81	800/reel	Tape reel
TO-220AB	MBR1545CTHE3/45 ⁽¹⁾	1.85	45	50/tube	Tube
ITO-220AB	MBRF1545CTHE3/45 ⁽¹⁾	1.99	45	50/tube	Tube
TO-263AB	MBRB1545CTHE3/45 ⁽¹⁾	1.35	45	50/tube	Tube
TO-263AB	MBRB1545CTHE3/81 ⁽¹⁾	1.35	81	800/reel	Tape reel

Note:

(1) Automotive grade AEC Q101 qualified



RATINGS AND CHARACTERISTICS CURVES

($T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)

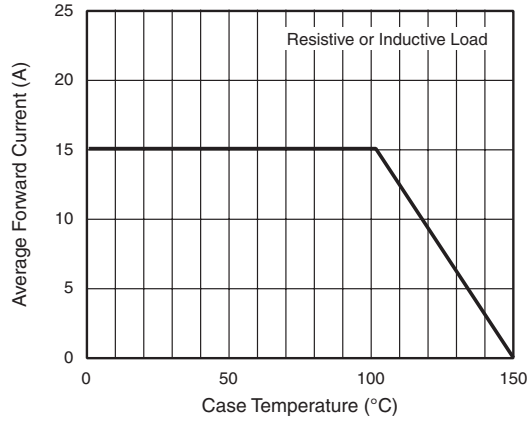


Figure 1. Forward Current Derating Curve

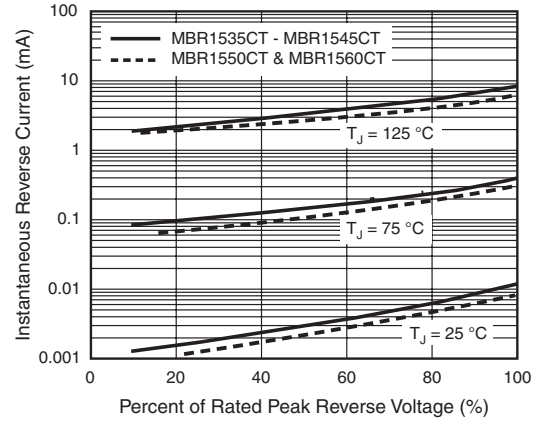


Figure 4. Typical Reverse Characteristics Per Diode

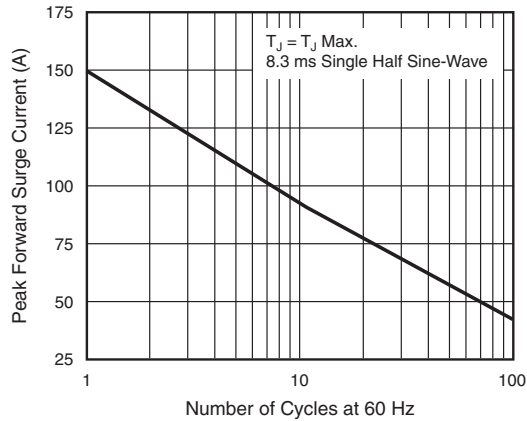


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

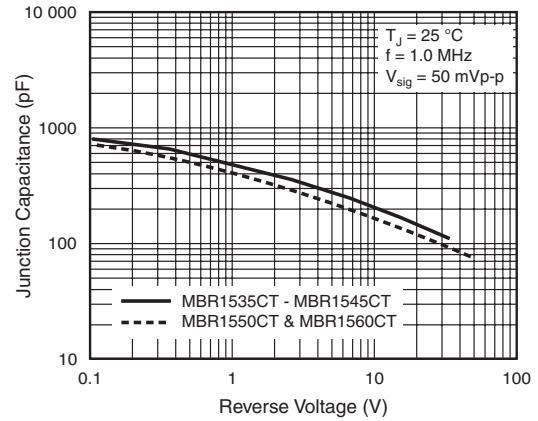


Figure 5. Typical Junction Capacitance Per Diode

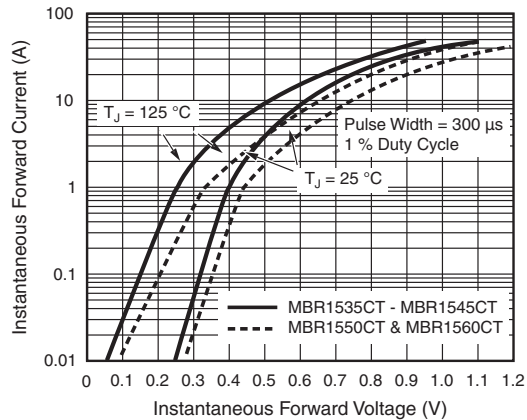


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

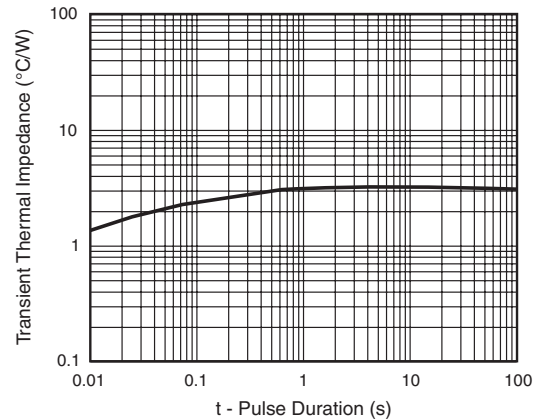


Figure 6. Typical Transient Thermal Impedance Per Diode

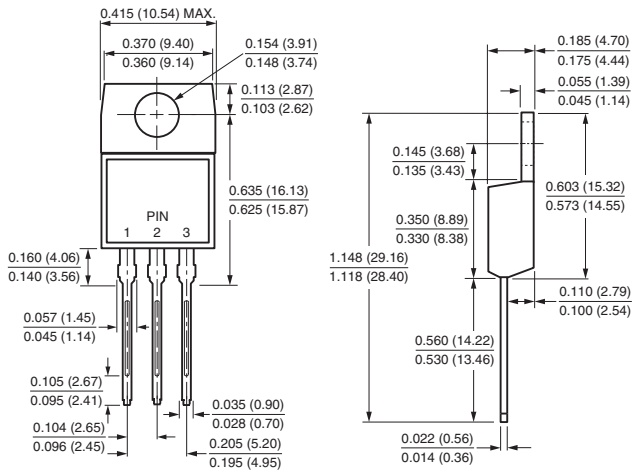
MBR(F,B)1535CT thru MBR(F,B)1560CT

Vishay General Semiconductor

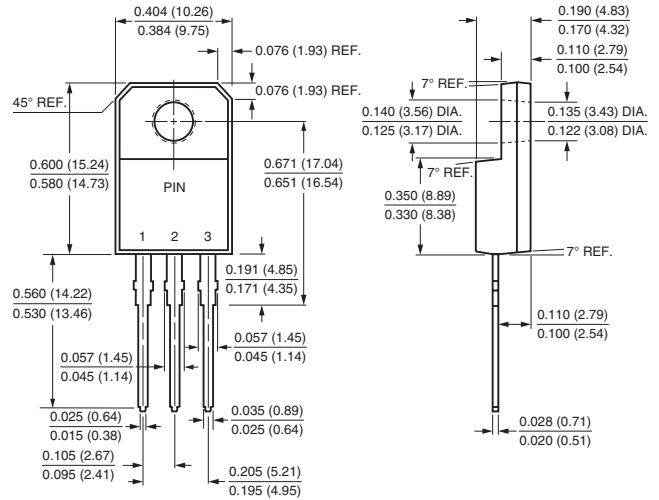


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

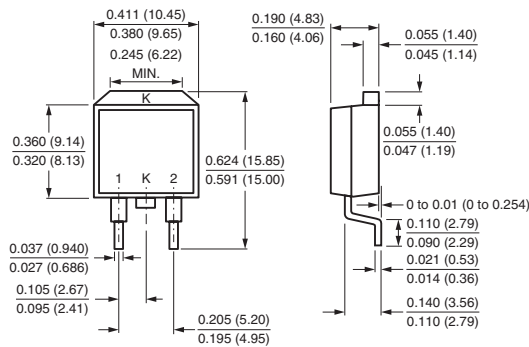
TO-220AB



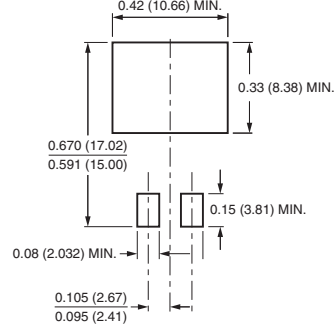
ITO-220AB



TO-263AB



Mounting Pad Layout





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